

Unravelling the Origins of Contact Recombination for Localized Laser-Doped Contacts

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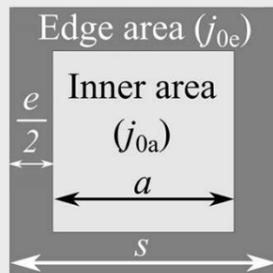
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Develop methodology and experiments for separating the edge and area contributions to the lumped recombination parameter of localized contacts

Methodology

- 1 Varying **edge-to-area ratio** ($\propto 1/s$) of localized contacts
- 2 Determine **lumped recombination parameter** $j_{0,ave}$ of localized contacts
- 3 Extract **edge recombination** $j_{0,e}$ and **area recombination** $j_{0,a}$ from slope and y-intercept of $j_{0,ave} \propto 1/s$

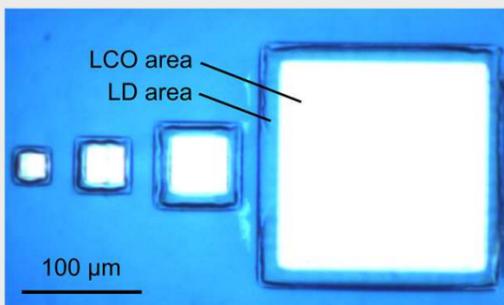


Assumptions

- 1 Area-proportional contribution of inner area $j_{0,a}$ and edge area $j_{0,e}$ to lumped recombination $j_{0,ave}$ with $\Delta j_0 = j_{0,e} - j_{0,a}$
- $$j_{0,ave} = j_{0,a} \frac{a^2}{s^2} + j_{0,e} \frac{s^2 - a^2}{s^2} = j_{0,a} + 2e\Delta j_0 \frac{s}{s^2} - e^2\Delta j_0 \frac{1}{s^2}$$
- 1 Total edge width $e = 4 \pm 2 \mu\text{m}$ (estimated from micro photoluminescence spectroscopy measurements)
 - 1 Linear approximation assuming $e \ll s$

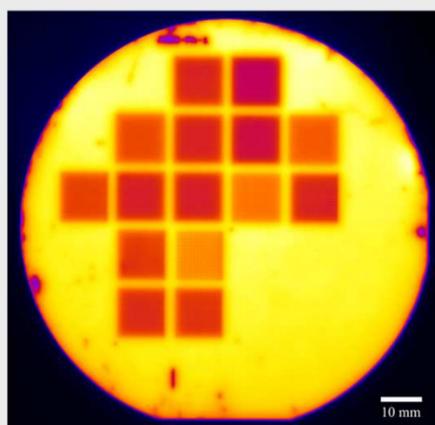
Experiment

- 1 **Localized contacts** with varying edge-to-area ratio fabricated by two-step laser process: **dope** / passivate / **ablate** (248-nm Excimer flat-top laser beam with variable aperture mask)



Microscope image illustrating the variation of laser-doping size after laser-contact opening confined to a region smaller than the laser-doped areas.

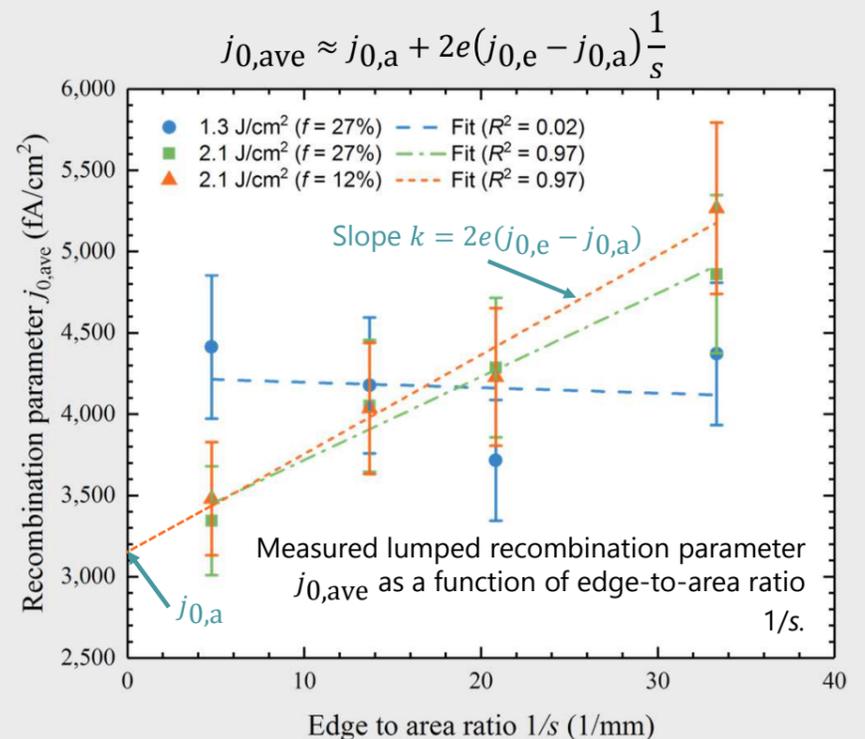
- 1 Samples with **regular pattern of localized contacts**, varying edge-to-area ratio (contact size) for **constant contact fraction** f and two **laser parameters** ϕ
- 1 Combination of **calibrated photoluminescence imaging** and **three-dimensional numerical simulations** to **extract** $j_{0,ave}$ of localized contacts [1]



PL image of local laser-doped contacts. The different processed square-shaped areas feature different laser spot sizes, pitches and laser fluences. The bottom right reference quarter is used for calibrating the method using QSSPC measurements.

Results

- 1 Fit of measured $j_{0,ave}$ using linear approximation



- 1 Due to uncertainty in e we determine the edge recombination using the implicit relation

$$j_{0,e} \equiv j_{0,e}(e) = j_{0,a} + \frac{k}{2e}$$

| Fluence ϕ | f | Area rec. $j_{0,a}$ | Slope k | Edge rec. $j_{0,e}$ |
|----------------------|-----|-----------------------|-------------------------|-----------------------|
| (J/cm ²) | (%) | (fA/cm ²) | (fA/cm ² mm) | (fA/cm ²) |
| 1.3 | 12 | 3,340* | - | - |
| 1.3 | 27 | 4,170* | - | - |
| 2.1 | 7 | 2,285 ± 115 | 72.7 ± 5.5 | 9,550 ± 4,480 |
| 2.1 | 12 | 2,658 ± 182 | 55.1 ± 8.7 | 11,370 ± 5,130 |
| 2.1 | 12 | 3,206 ± 132 | 51.2 ± 6.3 | 9,610 ± 4,600 |
| 2.1 | 27 | 3,145 ± 155 | 61.0 ± 7.4 | 10,770 ± 5,030 |

*Mean value of $j_{0,ave}$

Note that the laser doping process has not been optimized in this experiment.

Conclusion

- 1 **Varying the edge-to-area ratio** combined with measuring lumped recombination parameters of localized contacts **enables separation of edge and area contributions**
- 1 **Edge-recombination exceeds area-recombination by a factor greater than 3 to 4**
- 1 Further analysis required (e.g. by micro PL spectroscopy) to **accurately determine edge width e**

References

[1] M. Ernst et al., IEEE J. Photovoltaics 7 (2), 471–478 (2017).

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